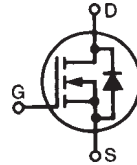


# Trench™ Power MOSFET

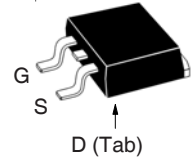
# IXTA80N10T IXTP80N10T

$V_{DSS} = 100V$   
 $I_{D25} = 80A$   
 $R_{DS(on)} \leq 14m\Omega$

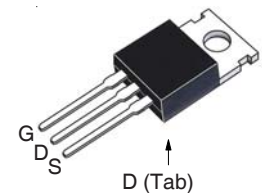
N-Channel Enhancement Mode  
 Avalanche Rated



TO-263  
(IXTA)



TO-220  
(IXTP)



G = Gate      D = Drain  
 S = Source    Tab = Drain

| Symbol     | Test Conditions  | Maximum Ratings    |            |
|------------|--|--------------------|------------|
|            |  |                    |            |
| $V_{DSS}$  | $T_J = 25^\circ C$ to $175^\circ C$                                | 100                | V          |
| $V_{DGR}$  | $T_J = 25^\circ C$ to $175^\circ C$ , $R_{GS} = 1M\Omega$          | 100                | V          |
| $V_{GSS}$  | Continuous   | $\pm 20$           | V          |
| $V_{GSM}$  | Transient  | $\pm 30$           | V          |
| $I_{D25}$  | $T_C = 25^\circ C$   | 80                 | A          |
| $I_{DM}$   | $T_C = 25^\circ C$ , Pulse Width Limited by $T_{JM}$               | 220                | A          |
| $I_A$      | $T_C = 25^\circ C$   | 25                 | A          |
| $E_{AS}$   | $T_C = 25^\circ C$   | 400                | mJ         |
| $dv/dt$    | $I_S \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 175^\circ C$ | 10                 | V/ns       |
| $P_D$      | $T_C = 25^\circ C$   | 230                | W          |
| $T_J$      |  | -55 ... +175       | $^\circ C$ |
| $T_{JM}$   |  | 175                | $^\circ C$ |
| $T_{stg}$  |  | -55 ... +175       | $^\circ C$ |
| $T_L$      | Maximum Lead Temperature for Soldering                             | 300                | $^\circ C$ |
| $T_{SOLD}$ | 1.6 mm (0.062in.) from Case for 10s                                | 260                | $^\circ C$ |
| $F_C$      | Mounting Force (TO-263)  | 10..65 / 2.2..14.6 | N/lb       |
| $M_d$      | Mounting Torque (TO-220)   | 1.13 / 10          | Nm/lb.in   |
| Weight     | TO-263   | 2.5                | g          |
|            | TO-220   | 3.0                | g          |

## Features

- Ultra-Low On Resistance
- Avalanche Rated
- Low Package Inductance
  - Easy to Drive and to Protect
- 175 $^\circ C$  Operating Temperature
- Fast Intrinsic Diode

## Advantages

- Easy to Mount
- Space Savings
- High Power Density

## Applications

- Automotive
  - Motor Drives
  - 42V Power Bus
  - ABS Systems
- DC/DC Converters and Off-line UPS
- Primary Switch for 24V and 48V Systems
- Distributed Power Architectures and VRMs
- Electronic Valve Train Systems
- High Current Switching Applications
- High Voltage Synchronous Rectifier

| Symbol       | Test Conditions<br>( $T_J = 25^\circ C$ Unless Otherwise Specified) | Characteristic Values |      |               |
|--------------|---|-----------------------|------|---------------|
|              |   | Min.                  | Typ. | Max.          |
| $BV_{DSS}$   | $V_{GS} = 0V$ , $I_D = 250\mu A$                                    | 105                   |      | V             |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 50\mu A$                                 | 2.5                   |      | 4.5 V         |
| $I_{GSS}$    | $V_{GS} = \pm 20V$ , $V_{DS} = 0V$                                  |                       |      | $\pm 200$ nA  |
| $I_{DSS}$    | $V_{DS} = 105V$ , $V_{GS} = 0V$<br>$T_J = 150^\circ C$              |                       |      | 5 $\mu A$     |
|              |   |                       |      | 150 $\mu A$   |
| $R_{DS(on)}$ | $V_{GS} = 10V$ , $I_D = 25A$ , Notes 1 & 2                          |                       |      | 14 m $\Omega$ |

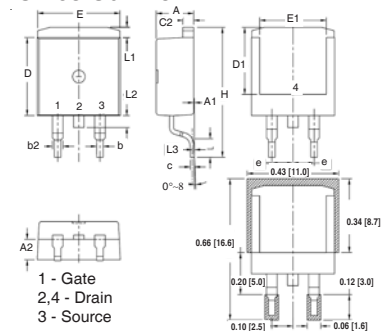
| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)  | Characteristic Values |      |                        |
|--------------|--|-----------------------|------|------------------------|
|              |  | Min.                  | Typ. | Max.                   |
| $g_{fs}$     | $V_{DS} = 10\text{V}$ , $I_D = 40\text{A}$ , Note 1  | 33                    | 55   | S                      |
| $C_{iss}$    | $V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$   |                       | 3040 | pF                     |
| $C_{oss}$    |  |                       | 420  | pF                     |
| $C_{rss}$    |  |                       | 90   | pF                     |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 10\text{A}$<br>$R_G = 15\Omega$ (External) |                       | 31   | ns                     |
| $t_r$        |  |                       | 54   | ns                     |
| $t_{d(off)}$ |  |                       | 40   | ns                     |
| $t_f$        |  |                       | 48   | ns                     |
| $Q_{g(on)}$  | $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 10\text{A}$  |                       | 60   | nC                     |
| $Q_{gs}$     |  |                       | 21   | nC                     |
| $Q_{gd}$     |  |                       | 15   | nC                     |
| $R_{thJC}$   |  |                       |      | $0.65^\circ\text{C/W}$ |
| $R_{thCH}$   | TO-220   | 0.50                  |      | $^\circ\text{C/W}$     |

### Source-Drain Diode

| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                          | Characteristic Values |      |       |
|----------|--|-----------------------|------|-------|
|          |  | Min.                  | Typ. | Max.  |
| $I_S$    | $V_{GS} = 0\text{V}$   |                       |      | 80 A  |
| $I_{SM}$ | Repetitive, Pulse Width Limited by $T_{JM}$  |                       |      | 220 A |
| $V_{SD}$ | $I_F = 25\text{A}$ , $V_{GS} = 0\text{V}$ , Note 1   |                       |      | 1.1 V |
| $t_{rr}$ | $I_F = 25\text{A}$ , $V_{GS} = 0\text{V}$<br>$-di/dt = 100\text{A}/\mu\text{s}$ , $V_R = 50\text{V}$ |                       | 100  | ns    |

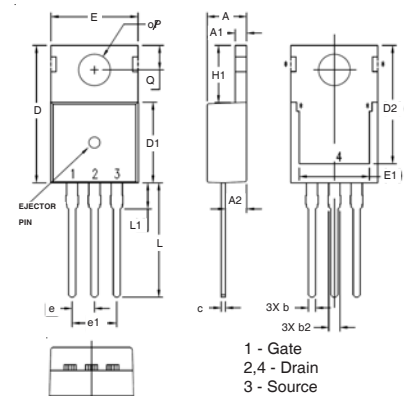
- Notes: 1. Pulse test,  $t \leq 300\mu\text{s}$ ; duty cycle,  $d \leq 2\%$ .  
2. On through-hole packages,  $R_{DS(on)}$  Kelvin test contact location must be 5mm or less from the package body.

### TO-263 Outline



| SYM | INCHES   |      | MILLIMETER |       |
|-----|----------|------|------------|-------|
|     | MIN      | MAX  | MIN        | MAX   |
| A   | .170     | .185 | 4.30       | 4.70  |
| A1  | .000     | .008 | 0.00       | 0.20  |
| A2  | .091     | .098 | 2.30       | 2.50  |
| b   | .028     | .035 | 0.70       | 0.90  |
| b2  | .046     | .060 | 1.18       | 1.52  |
| C   | .018     | .024 | 0.45       | 0.60  |
| C2  | .049     | .060 | 1.25       | 1.52  |
| D   | .340     | .370 | 8.63       | 9.40  |
| D1  | .300     | .327 | 7.62       | 8.30  |
| E   | .380     | .410 | 9.65       | 10.41 |
| E1  | .270     | .330 | 6.86       | 8.38  |
| e   | .100 BSC |      | 2.54 BSC   |       |
| H   | .580     | .620 | 14.73      | 15.75 |
| L   | .075     | .105 | 1.91       | 2.67  |
| L1  | .039     | .060 | 1.00       | 1.52  |
| L2  | —        | .070 | —          | 1.77  |
| L3  | .010 BSC |      | 0.254 BSC  |       |

### TO-220 Outline



| SYM  | INCHES   |      | MILLIMETERS |       |
|------|----------|------|-------------|-------|
|      | MIN      | MAX  | MIN         | MAX   |
| A    | .169     | .185 | 4.30        | 4.70  |
| A1   | .047     | .055 | 1.20        | 1.40  |
| A2   | .079     | .106 | 2.00        | 2.70  |
| b    | .024     | .039 | 0.60        | 1.00  |
| b2   | .045     | .057 | 1.15        | 1.45  |
| c    | .014     | .026 | 0.35        | 0.65  |
| D    | .587     | .626 | 14.90       | 15.90 |
| D1   | .335     | .370 | 8.50        | 9.40  |
| (D2) | .500     | .531 | 12.70       | 13.50 |
| E    | .382     | .406 | 9.70        | 10.30 |
| (E1) | .283     | .323 | 7.20        | 8.20  |
| e    | .100 BSC |      | 2.54 BSC    |       |
| e1   | .200 BSC |      | 5.08 BSC    |       |
| H1   | .244     | .268 | 6.20        | 6.80  |
| L    | .492     | .547 | 12.50       | 13.90 |
| L1   | .110     | .154 | 2.80        | 3.90  |
| ∅P   | .134     | .150 | 3.40        | 3.80  |
| Q    | .106     | .126 | 2.70        | 3.20  |

IXYS reserves the right to change limits, test conditions, and dimensions.

Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$

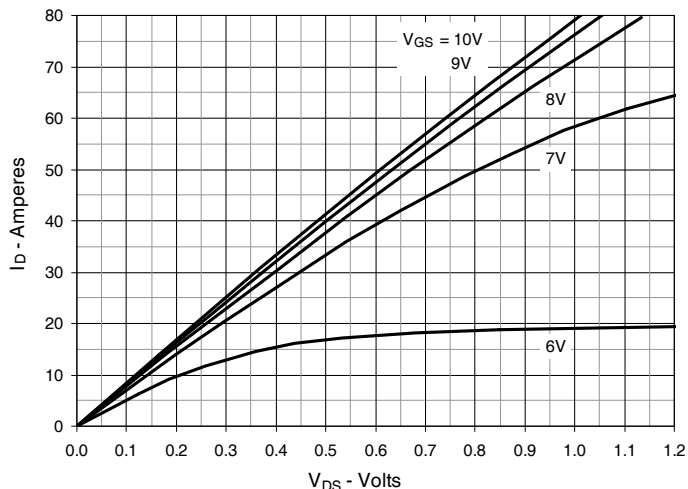


Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$

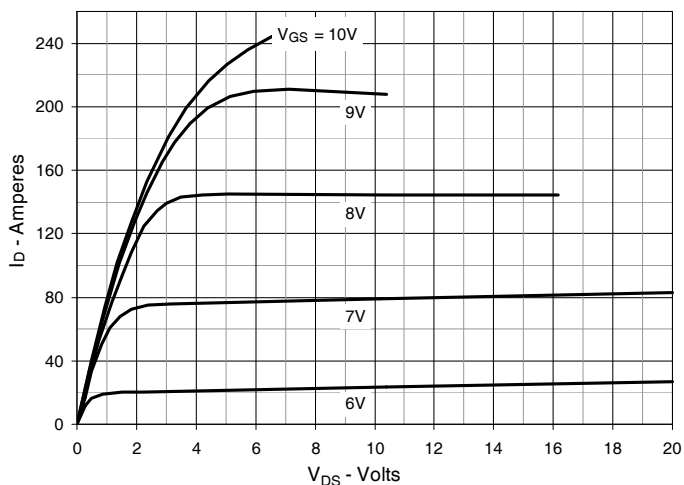


Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$

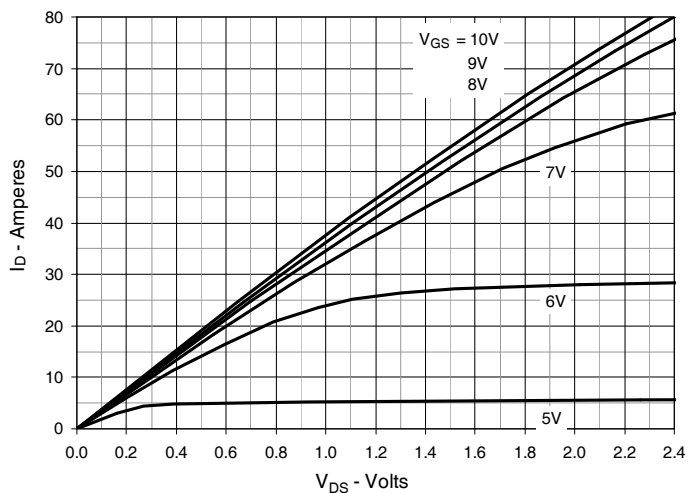


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 40\text{A}$  Value vs. Junction Temperature

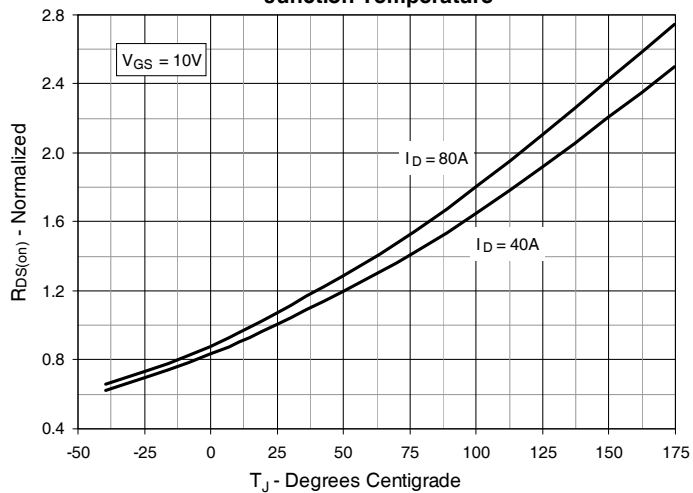


Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 40\text{A}$  Value vs. Drain Current

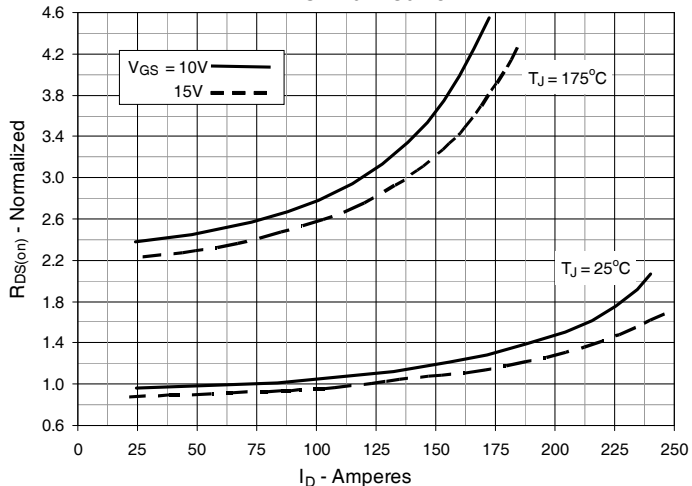
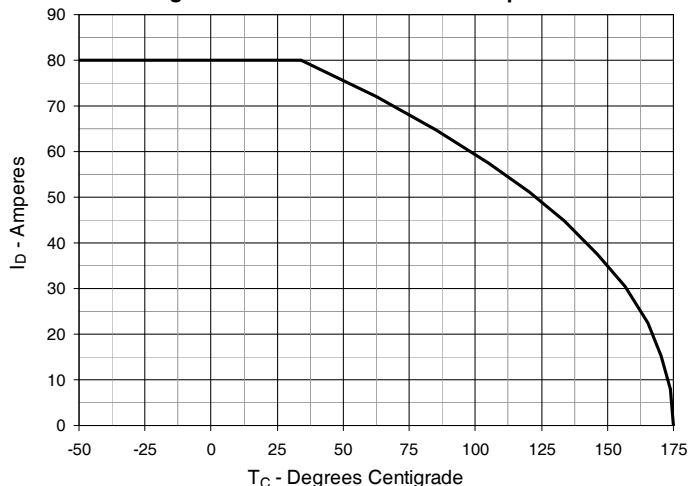
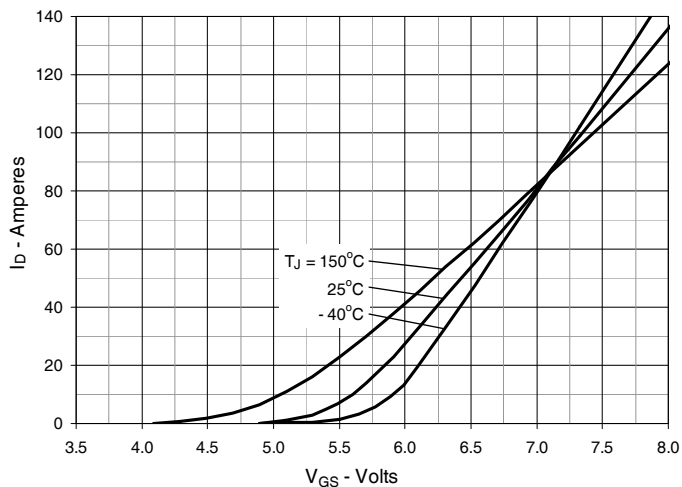


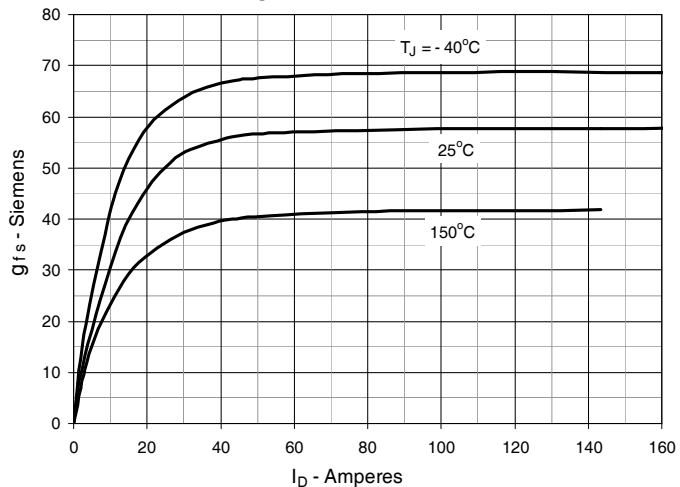
Fig. 6. Drain Current vs. Case Temperature



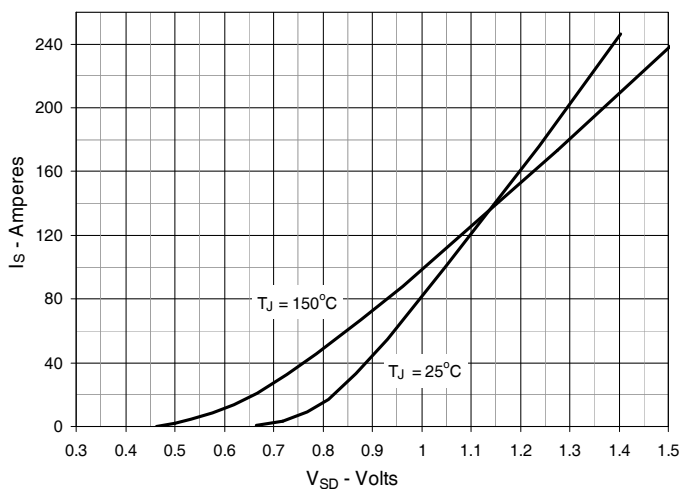
**Fig. 7. Input Admittance**



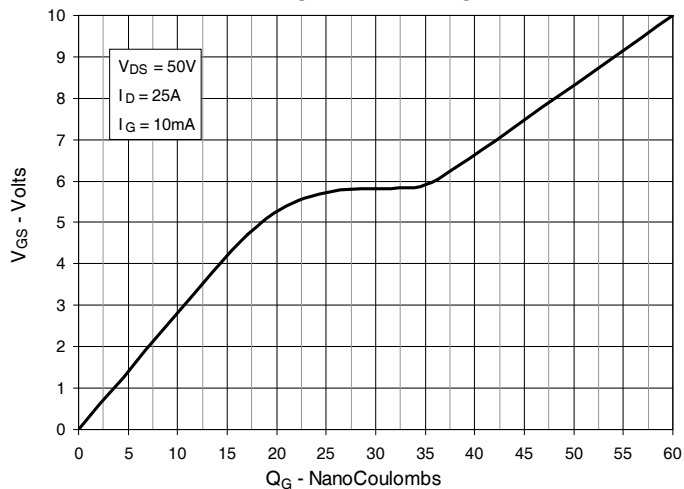
**Fig. 8. Transconductance**



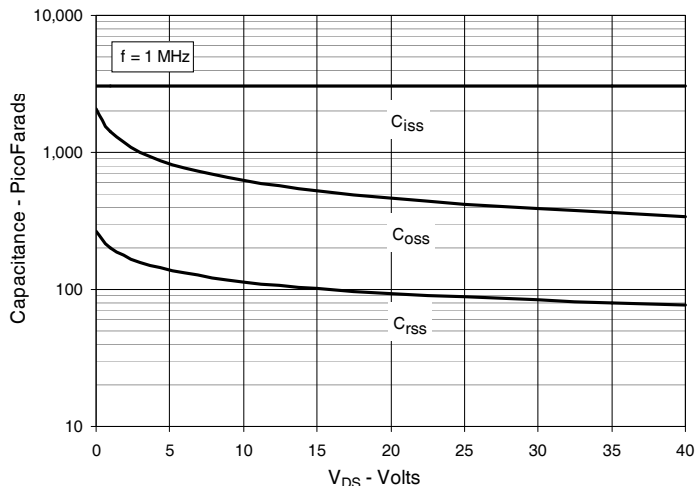
**Fig. 9. Forward Voltage Drop of Intrinsic Diode**



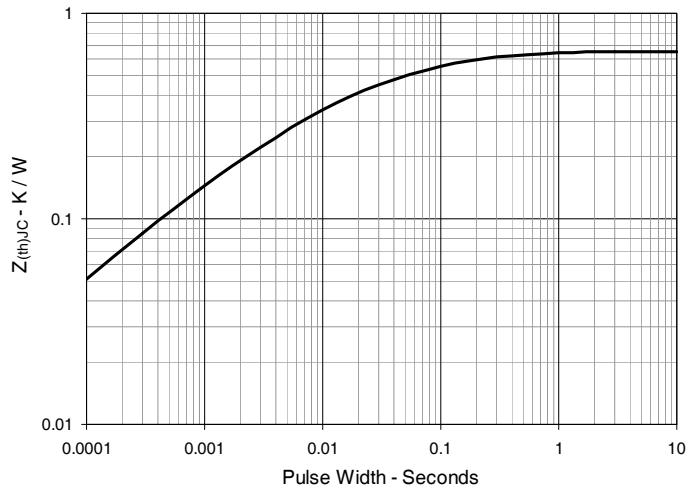
**Fig. 10. Gate Charge**



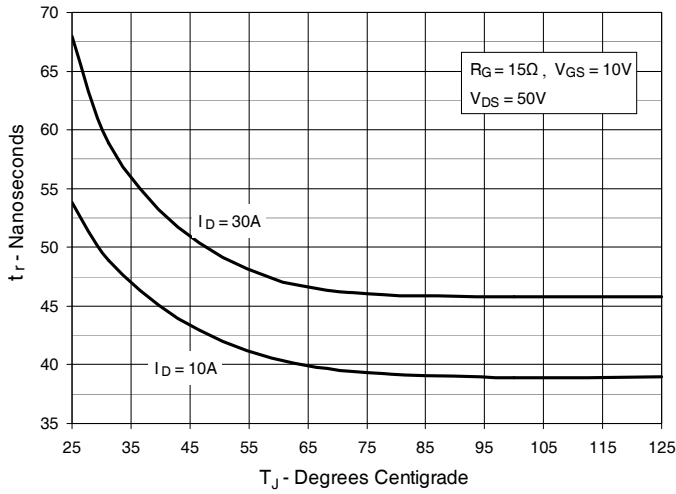
**Fig. 11. Capacitance**



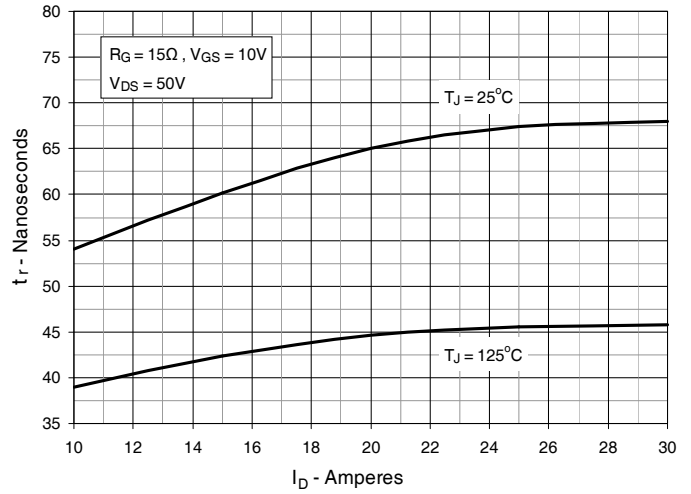
**Fig. 12. Maximum Transient Thermal Impedance**



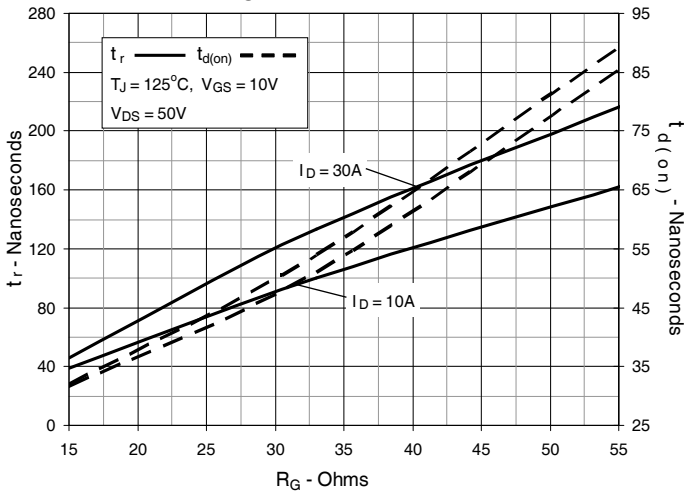
**Fig. 13. Resistive Turn-on**  
**Rise Time vs. Junction Temperature**



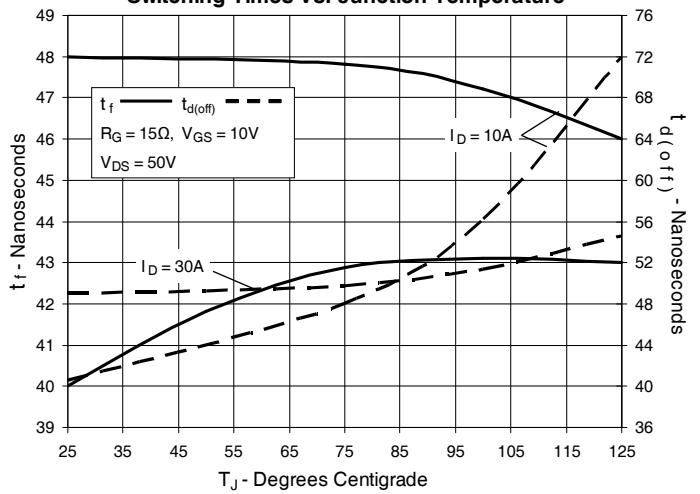
**Fig. 14. Resistive Turn-on**  
**Rise Time vs. Drain Current**



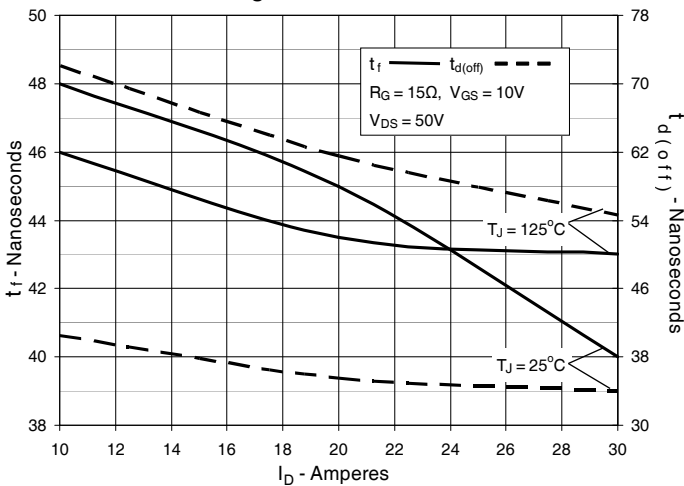
**Fig. 15. Resistive Turn-on**  
**Switching Times vs. Gate Resistance**



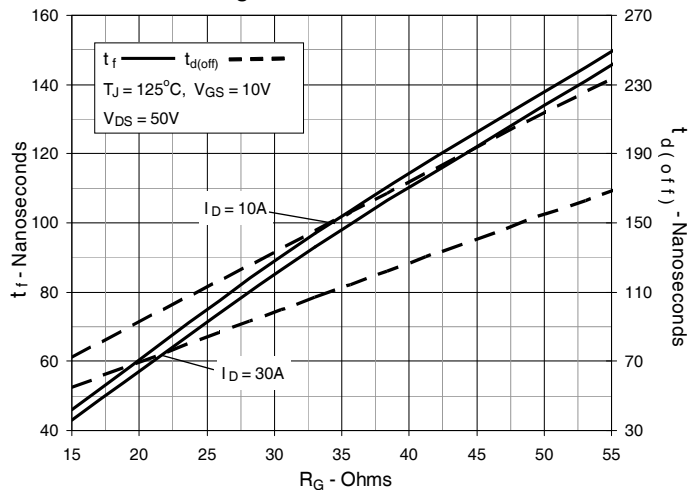
**Fig. 16. Resistive Turn-off**  
**Switching Times vs. Junction Temperature**



**Fig. 17. Resistive Turn-off**  
**Switching Times vs. Drain Current**



**Fig. 18. Resistive Turn-off**  
**Switching Times vs. Gate Resistance**





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